GN02024B

GaAs IC (with built-in ferroelectric)

Mixer with local amplifier for cellular phone

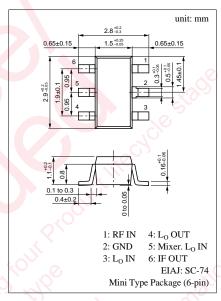
■ Features

● Low distortion mixer (DCS-1800)

● Small package: Mini 6pin

■ Absolute Maximum Ratings (Ta = 25°C)

Parameter	Symbol	Ratings Unit		
	V _{in}	-3	V	
RF section	I _{in}	1	mA	
	Pin	10	dBm	
	V _{in}	-3	V	
L _O input section	I _{in}	1	mA	
	P _{in}	10	dBm	
L _O output section	V _{out}	5	V	
	I _{out}	10	mA	
$Mix \cdot L_O$ section	V _{in}	-3	V	
	I _{in}	1	mA	
IF section	V _{out}	5	V	
	I _{out}	10	mA	
Overall	P _T	0.1	W	
	T _{ch}	150	°C	
	T _{stg}	-55 to +150	°C	



Marking Symbol: KR

■ Electrical Characteristics (Ta = 25 ± 3°C)

Parameter	Symbol	Conditions	min	typ	max	Unit
Mixer current	IMix	VIF _{out} = 2.8V	3.5	5.4	7.3	mA
Local amplifier current	ILo	$VL_{Oout} = 2.8V$	0.9	2	3.1	mA
Conversion gain	CG*1	$VIF_{out} = VL_{Oout} = 2.8V$ $f_{LO} = 1596 \text{ to } 1634\text{MHz}$ f = 1805 to 1880MHz $P_{LO} = -10\text{dBm}, P = -25\text{dBm}$	6		12	dB
Input third harmonics mutual	IIP ₃₋₁ *1, 2	$VIF_{out} = VL_{Oout} = 2.8V$ $f_{LO} = 1559MHz, P_{LO} = -10dBm$ $f_{RF1} = 1805.8MHz, P_{RF1} = -25dBm$ $f_{RF2} = 1806.6MHz, P_{RF2} = -25dBm$	-3	-1		dBm
modulation distortion	IIP ₃₋₂ *1, 2	$\begin{aligned} & \text{VIF}_{\text{out}} = \text{VL}_{\text{Oout}} = 2.8\text{V} \\ & \text{f}_{\text{LO}} = 1634\text{MHz}, \text{P}_{\text{LO}} = -10\text{dBm} \\ & \text{f}_{\text{RF1}} = 1879.2\text{MHz}, \text{P}_{\text{RF1}} = -25\text{dBm} \\ & \text{f}_{\text{RF2}} = 1878.4\text{MHz}, \text{P}_{\text{RF2}} = -25\text{dBm} \end{aligned}$	-3	-1		dBm
Placking	*1, 2, 3	$\begin{split} VIF_{out} &= VL_{Oout} = 2.8V \\ f_{LO} &= 1559 MHz, P_{LO} = -10 dBm \\ f_{RF1} &= 1805 MHz, P_{RF1} = -80 dBm \\ f_{RF2} &= 1808 MHz, P_{RF2} = -9 dBm \end{split}$			3	dBc
Blocking	*1, 2, 3	$VIF_{out} = VL_{Oout} = 2.8V$ $f_{LO} = 1634MHz, P_{LO} = -10dBm$ $f_{RF1} = 1880MHz, P_{RF1} = -80dBm$ $f_{RF2} = 1877MHz, P_{RF2} = -9dBm$			3	dBc

^{*1} Refer to measurement circuit.

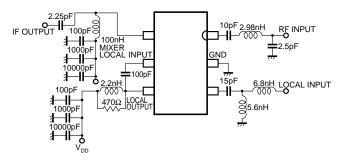
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^{*2} Sampling guaranteed items. (AQL = 0.65%)

 $^{^{\}ast 3}$ Suppression ratio of f_{RF2} when the signals of f_{RF1} and f_{RF2} are fed.

GaAs MMICs GN02024B

■ Measurement Circuit



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